


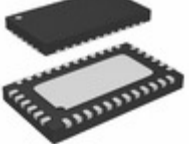





	<h2>SI3454ADV-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI3454ADV-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 30V 3.4A 6-TSOP</p> <p>Datenblätter:  SI3454ADV-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 49954 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI3454ADV-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 30V 3.4A 6-TSOP
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	49954 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SOT-23-6 Thin, TSOT-23-6
Supplier Device-Gehäuse	6-TSOP
Verlustleistung (max)	1.14W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.4A (Ta)
Rds On (Max) @ Id, Vgs	60 mOhm @ 4.5A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)


















































SI3454ADV-T1-E3 ist neu im Original, Suche SI3454ADV-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI3454ADV-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI3454ADV-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI3454-KIT Energy Micro (Silicon Labs) EVAL KIT FOR SI3454 POE CTRLR</p>	 <p>SI3454ADV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 3.4A 6- TSOP</p>	 <p>SI3454-B01-IMR Energy Micro (Silicon Labs) IC POE PSE 4 PORT 802.3AT 38QFN</p>	 <p>SI3454CDV-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 4.2A 6TSOP</p>
 <p>SI3454ADV-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 3.4A 6TSOP</p>	 <p>SI3454CDV-T1-GE3 Vishay / Siliconix MOSFET N-CH 30V 4.2A 6TSOP</p>	 <p>SI3454CDV-T1-E3 Vishay / Siliconix MOSFET N-CH 30V 4.2A 6TSOP</p>	 <p>SI3454ADV-T1 VISHAY SI3454ADV-T1 VISHAY</p>

heiße Teile

Mehr

 SI3447BDV-T1-GE3	 SI3447BDV-T1-GE3	 SI3447BDV-T1-GE3	 SI3447CDV-T1	 SI3447CDV-T1-E3
 SI3447CDV-T1-E3	 SI3447CDV-T1-E3	 SI3447CDV-T1-E3	 SI3447DV	 SI3447DV-NL
 SI3447DV-T1	 SI3447DV-T1-E3	 SI3447DV-T1-GE3	 SI3448DV	 SI3448DV-T1-E3
 SI3451DV-T1-E3	 SI3451DV-T1-E3	 SI3451DV-T1-E3	 SI3451DV-T1-GE3	 SI3452DV-T1-E3
 SI3453DV-T1-GE3	 SI3453DV-T1-GE3	 SI3453DV-T5-GE3	 SI3454ADV-T1	 SI3454ADV-T1-E3
 SI3454ADV-T1-GE3	 SI3454ADV-T1-GE3	 SI3454CDV-T1-GE3	 SI3454CDV-T1-GE3	 SI3454DV-NL
 SI3454DV-T1	 SI3454DV-T1-E3	 SI3455ADV-T1-E3	 SI3455ADV-T1-E3	 SI3455ADV-T1-GE3
 SI3455ADV-T1-GE3	 SI3455DV-NL	 SI3455DV-T1-E3	 SI3455DV-T1-GE3	 SI3456-C02-GU
 SI3456-E04-GU	 SI3456BD-T1-E3	 SI3456BDV-T1	 SI3456BDV-T1-E3	 SI3456BDV-T1-E3
 SI3456BDV-T1-GE3	 SI3456BDV-T1-GE3	 SI3456CDV-T1-E3	 SI3456CDV-T1-E3	 SI3456CDV-T1-GE3

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

Copyright © 2019 YIC International Co., Limited